

Fast Recovery Diodes (Stud Version), 6 A/12 A/16 A



DO-203AA (DO-4)

FEATURES

- Short reverse recovery time
- Low stored charge
- Wide current range
- Excellent surge capabilities
- Standard JEDEC types
- Stud cathode and stud anode versions
- Fully characterized reverse recovery conditions
- Compliant to RoHS directive 2002/95/EC



RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$

6 A/12 A/16 A

TYPICAL APPLICATIONS

- DC power supplies
- Inverters
- Converters
- Choppers
- Ultrasonic systems
- Freewheeling diodes

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	6FL..	12FL..	16FL..	UNITS
$I_{F(AV)}$	$T_C = 100\text{ }^{\circ}\text{C}$	6	12	16	A
$I_{F(RMS)}$		9.5	19	25	A
I_{FSM}	50 Hz	110	145	180	A
	60 Hz	115	150	190	
I^2t	50 Hz	60	103	160	A^2s
	60 Hz	55	94	150	
$I^2\sqrt{t}$		1452	1452	2290	$\text{I}^2\sqrt{\text{s}}$
V_{RRM}	Range	50 to 1000			V
t_{rr}		See Recovery Characteristics table			ns
T_J	Range	- 65 to 150			$^{\circ}\text{C}$

6FL(R), 12FL(R), 16FL(R) Series

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = 25\text{ }^{\circ}\text{C}$ μA	I_{RRM} MAXIMUM AT $T_J = 100\text{ }^{\circ}\text{C}$ mA	I_{RRM} MAXIMUM AT $T_J = 150\text{ }^{\circ}\text{C}$ mA
6FL.. 12FL.. 16FL..	5	50	75	50	-	6.0
	10	100	150			
	20	200	275			
	40	400	500			
	60	600	725			
	80	800	950			
	100	1000	1250			

FORWARD CONDUCTION									
PARAMETER	SYMBOL	TEST CONDITIONS			6FL..	12FL..	16FL..	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave DC			6	12 ⁽¹⁾	16	A	
					100	100	100	°C	
Maximum RMS current	I _{F(RMS)}				9.5	19	25	A	
Maximum peak, one-cycle non-repetitive forward current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = 150 °C	130	170	215		
		t = 8.3 ms			135	180	225		
		t = 10 ms	100 % V _{RRM} reapplied		110	145	180		
		t = 8.3 ms			115	150 ⁽¹⁾	190		
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		86	145	230	A ² s	
		t = 8.3 ms			78	130	210		
		t = 10 ms	100 % V _{RRM} reapplied		60	103	160		
		t = 8.3 ms			55	94	150		
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			856	1452	2290	A ² √s	
Maximum forward voltage drop	V _{FM}	T _J = 25 °C; I _F = Rated I _{F(AV)} (DC)			1.4	1.4 ⁽¹⁾	1.4	V	
		T _C = 100 °C; I _{FM} = π x rated I _{F(AV)}			1.5	1.5 ⁽¹⁾	1.5		

Note

⁽¹⁾ JEDEC registered values

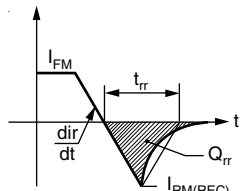


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Vishay Semiconductors

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	6FL... 12FL... 16FL...		UNITS	
			S02	S05		
Maximum reverse recovery time	t _{rr}	T _J = 25 °C, I _F = 1 A to V _R = 30 V, di _F /dt = 100 A/μs	-	-	ns	
		T _J = 25 °C, di _F /dt = 25 A/μs, I _{FM} = π x rated I _{F(AV)}	200	500		
Maximum peak recovery current	I _{RM(REC)}	I _{FM} = π x rated I _{F(AV)}	-		-	
Maximum reverse recovery charge	Q _{rr}	T _J = 25 °C, I _F = 1 A to V _R = 30 V, di _F /dt = 100 A/μs	-	-	nC	
		T _J = 25 °C, di _F /dt = 25 A/μs, I _{FM} = π x rated I _{F(AV)}	-	-		

Note

(1) JEDEC registered values

THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	6FL..	12FL..	16FL..	UNITS
Maximum junction operating temperature range	T _J		- 65 to 150			°C
Maximum storage temperature range	T _{Stg}		- 65 to 175			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	2.0	1.6	°C/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.5			
Allowable mounting torque		Not lubricated threads	1.5 + 0 - 10 % (13)			N · m (lbf · in)
		Lubricated threads	1.2 + 0 - 10 % (10)			
Approximate weight			7			g
			0.25			oz.
Case style		JEDEC	DO-203AA (DO-4)			

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Vishay Semiconductors

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(Stud Version), 6 A/12 A/16 A



ΔR_{thJC} CONDUCTION								
CONDUCTION ANGLE	6FL..	12FL..	16FL..	6FL..	12FL..	16FL..	TEST CONDITIONS	UNITS
	SINUSOIDAL CONDUCTION			RECTANGULAR CONDUCTION				
180°	0.58	0.46	0.37	0.33	0.26	0.21	T _J = 150 °C	K/W
120°	0.60	0.48	0.39	0.58	0.46	0.37		
60°	1.28	1.02	0.82	1.28	1.02	0.82		
30°	2.20	1.76	1.41	2.20	1.76	1.41		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

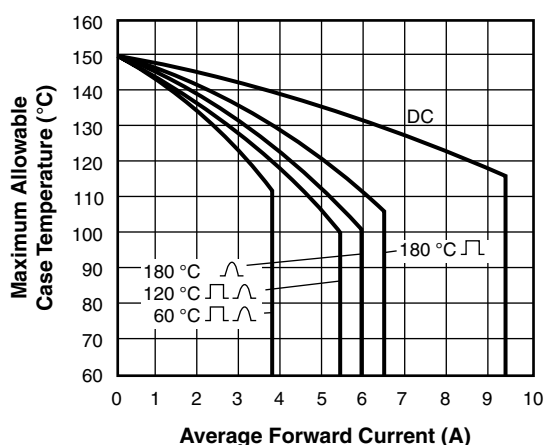


Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature, 6FL Series

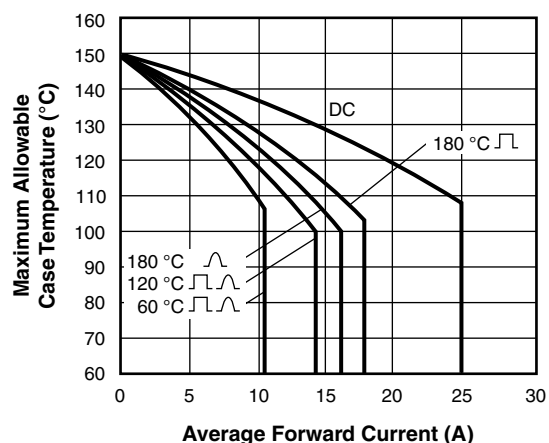


Fig. 3 - Average Forward Current vs. Maximum Allowable Case Temperature, 16FL Series

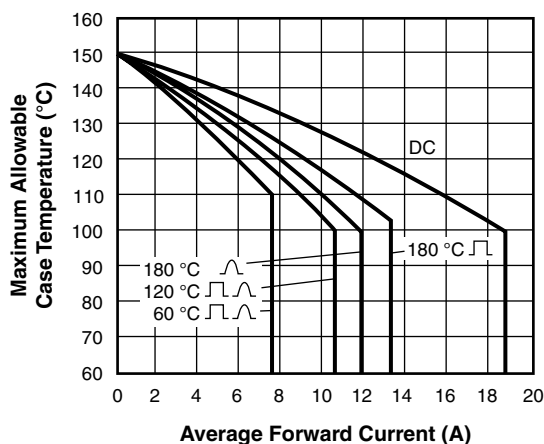


Fig. 2 - Average Forward Current vs. Maximum Allowable Case Temperature, 12FL Series

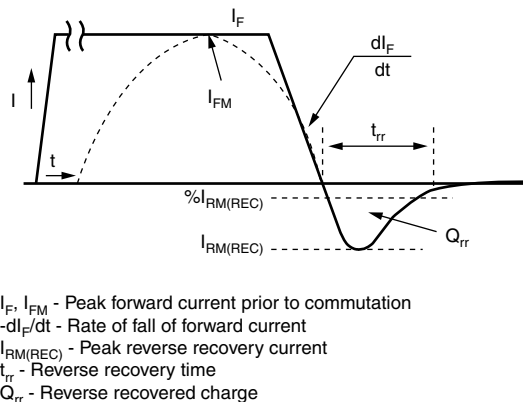


Fig. 4 - Reverse Recovery Time Test Waveform



6FL(R), 12FL(R), 16FL(R) Series

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Vishay Semiconductors

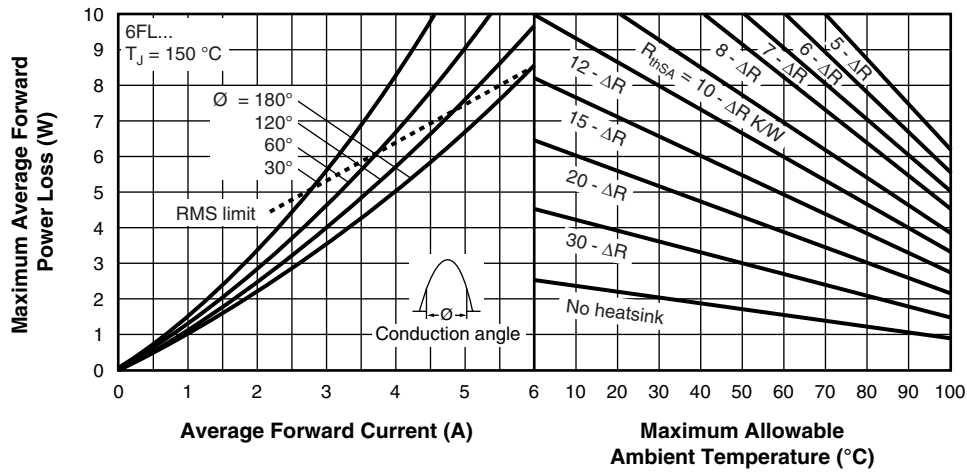


Fig. 5 - Current Rating Nomogram (Sinusoidal Waveforms), 6FL Series

Conduction angle - ϕ	ΔR - K/W
180°	0.58
120°	0.60
60°	1.28
30°	2.20

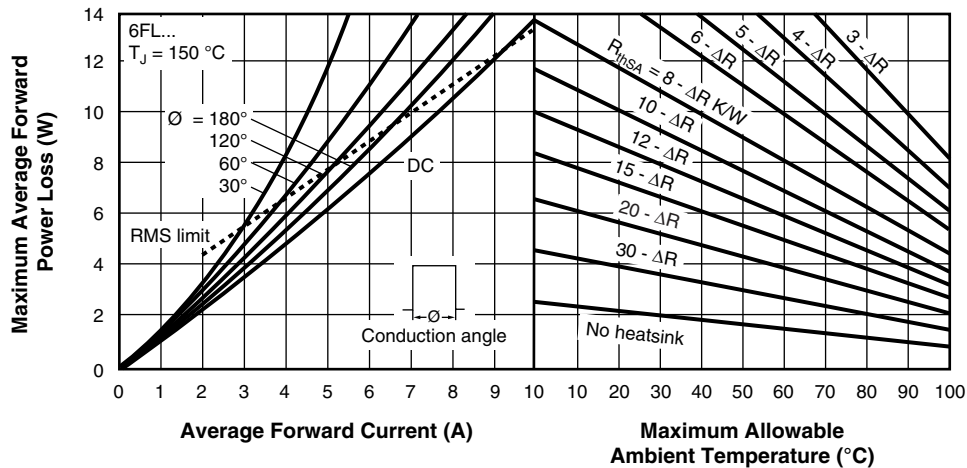


Fig. 6 - Current Rating Nomogram (Rectangular Waveforms), 6FL Series

Conduction angle - ϕ	ΔR - K/W
DC	0
180°	0.33
120°	0.58
60°	1.28
30°	2.20

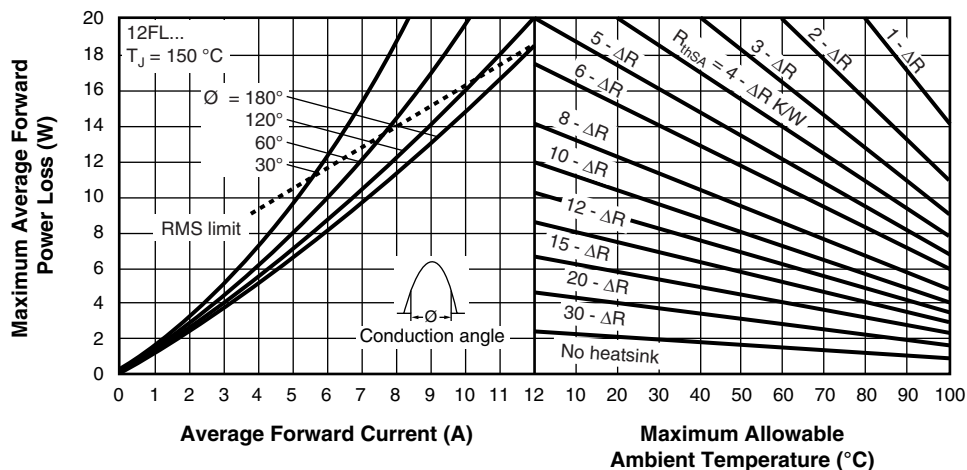


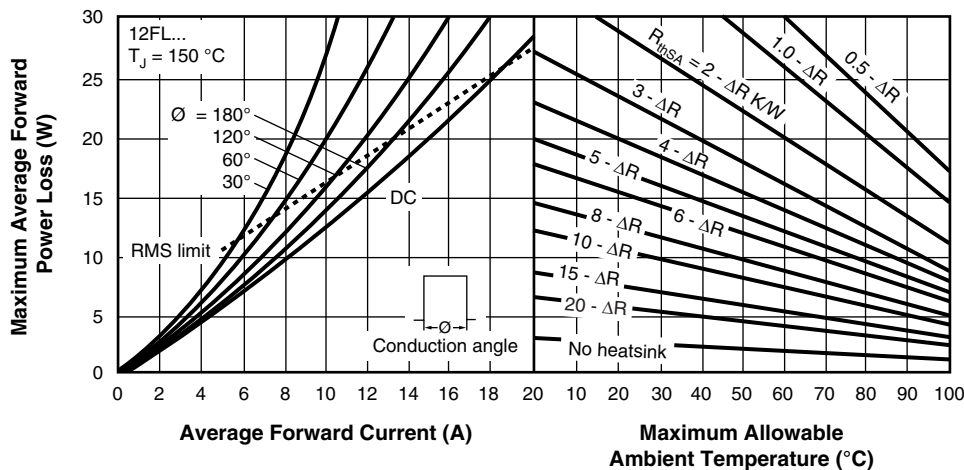
Fig. 7 - Current Rating Nomogram (Sinusoidal Waveforms), 12FL Series

Conduction angle - ϕ	ΔR - K/W
180°	0.46
120°	0.48
60°	1.02
30°	1.76

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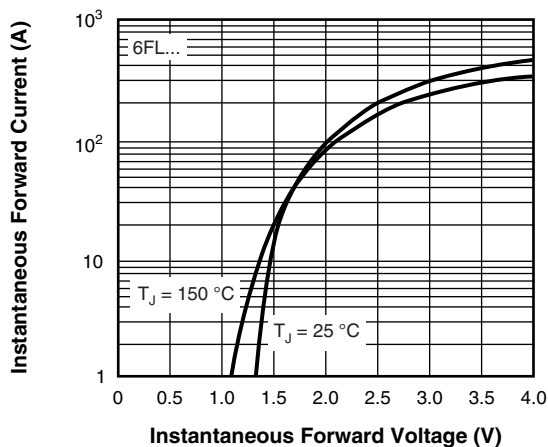


Fig. 11 - Maximum Forward Voltage vs. Forward Current, 6FL Series

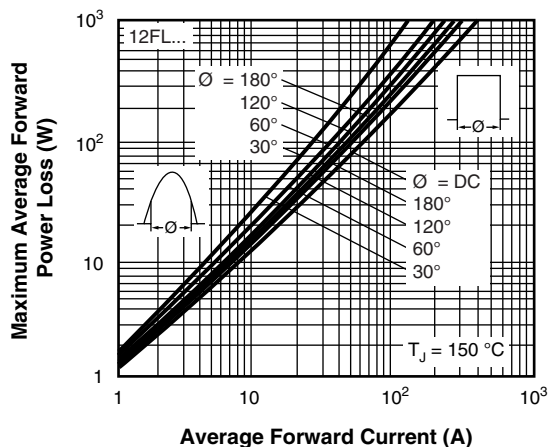


Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 12FL Series

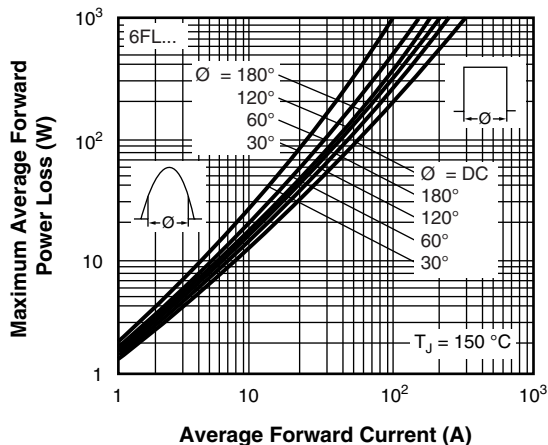


Fig. 12 - Maximum High Level Forward Power Loss vs. Average Forward Current, 6FL Series

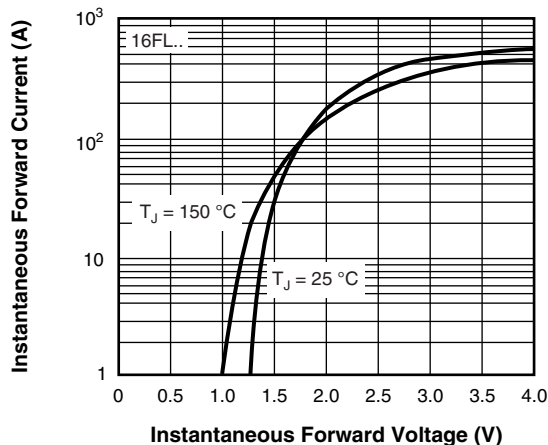


Fig. 15 - Maximum Forward Voltage vs. Forward Current, 16FL Series

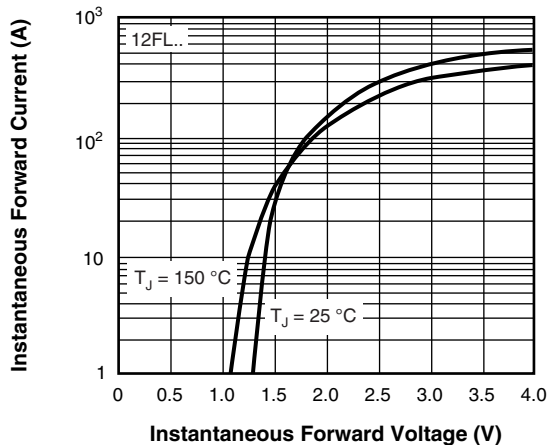


Fig. 13 - Maximum Forward Voltage vs. Forward Current, 12FL Series

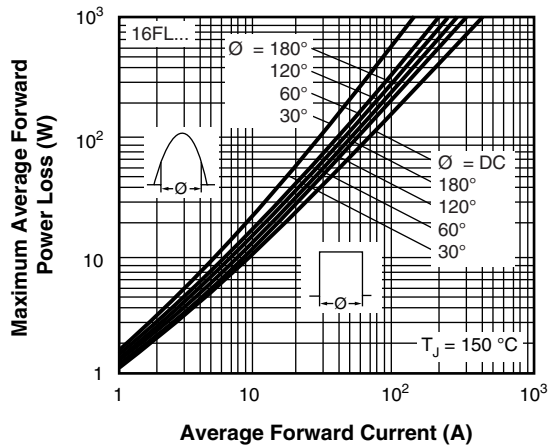


Fig. 16 - Maximum High Level Forward Power Loss vs. Average Forward Current, 16FL Series

6FL(R), 12FL(R), 16FL(R) Series

Vishay Semiconductors

Fast Recovery Diodes
(Stud Version), 6 A/12 A/16 A

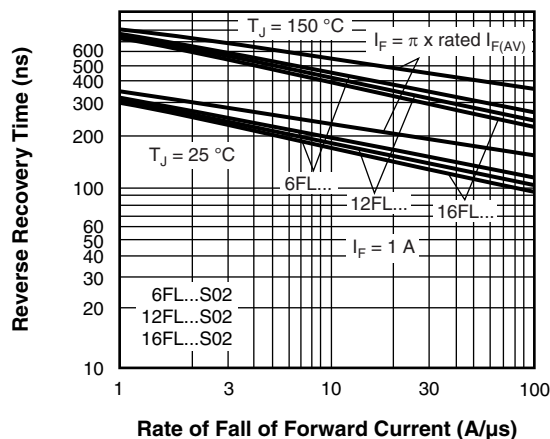


Fig. 17a - Typical Reverse Recovery Time vs. Rate of Fall of Forward Current, All Series ...S02

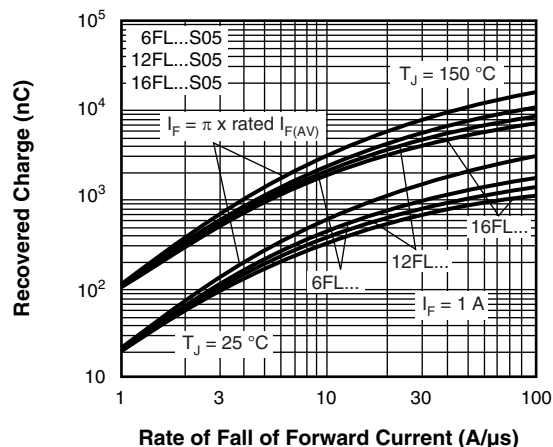


Fig. 18b - Typical Recovered Charge vs. Rate of Fall of Forward Current, All Series ...S05

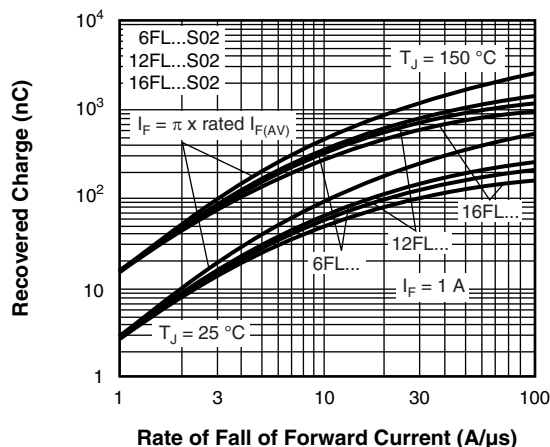


Fig. 17b - Typical Recovered Charge vs. Rate of Fall of Forward Current, All Series ...S02

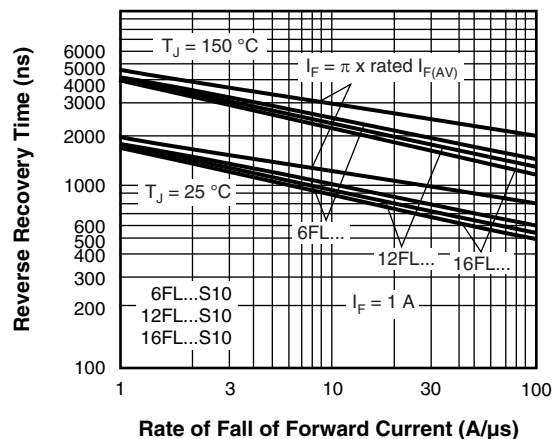


Fig. 19a - Typical Reverse Recovery Time vs. Rate of Fall of Forward Current, All Series ...S10

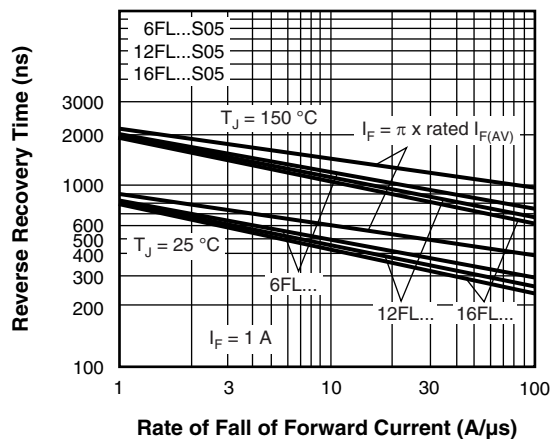


Fig. 18a - Typical Reverse Recovery Time vs. Rate of Fall of Forward Current, All Series ...S05

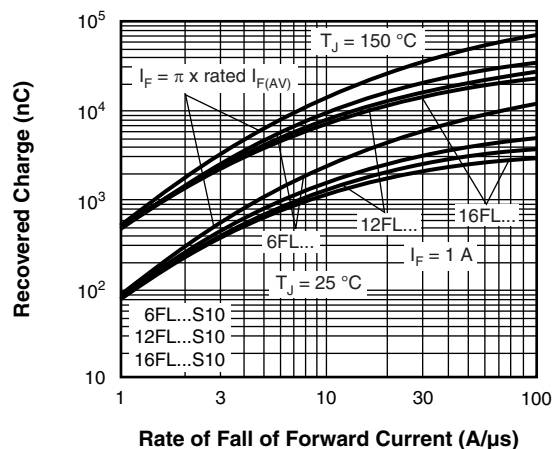


Fig. 19b - Typical Recovered Charge vs. Rate of Fall of Forward Current, All Series ...S10

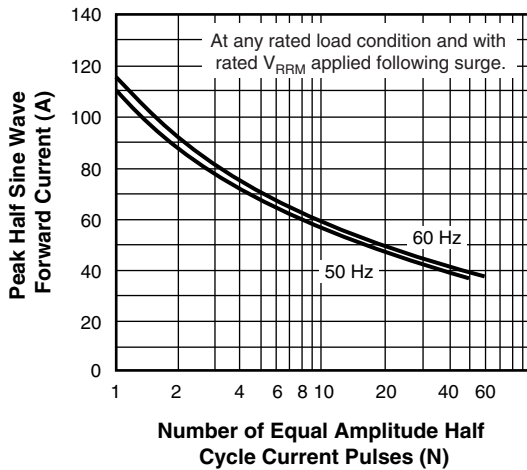


Fig. 20 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 6FL Series

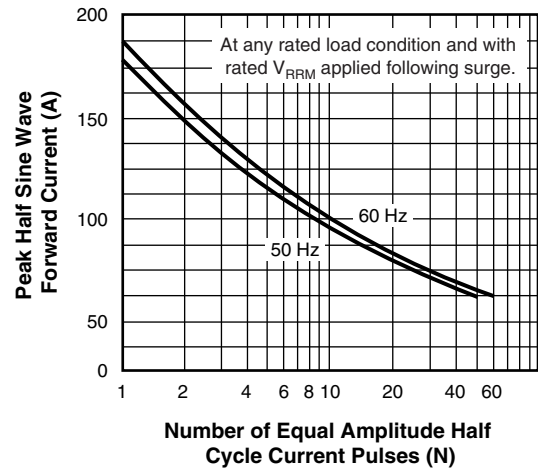


Fig. 22 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 16FL Series

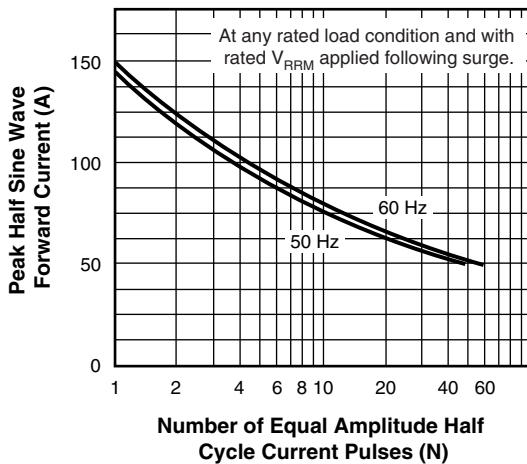


Fig. 21 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 12FL Series

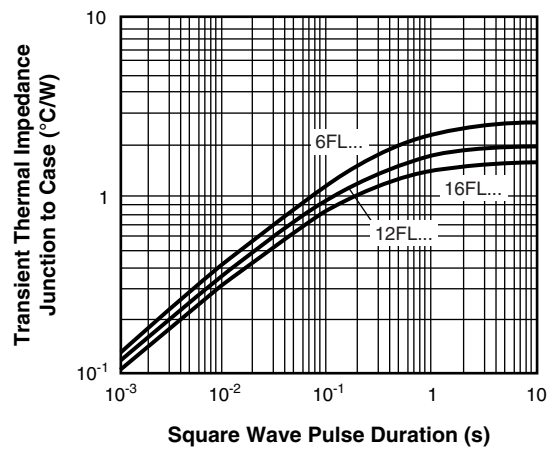


Fig. 23 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration, All Series

6FL(R), 12FL(R), 16FL(R) Series



Vishay Semiconductors

Fast Recovery Diodes
(Stud Version), 6 A/12 A/16 A

ORDERING INFORMATION TABLE

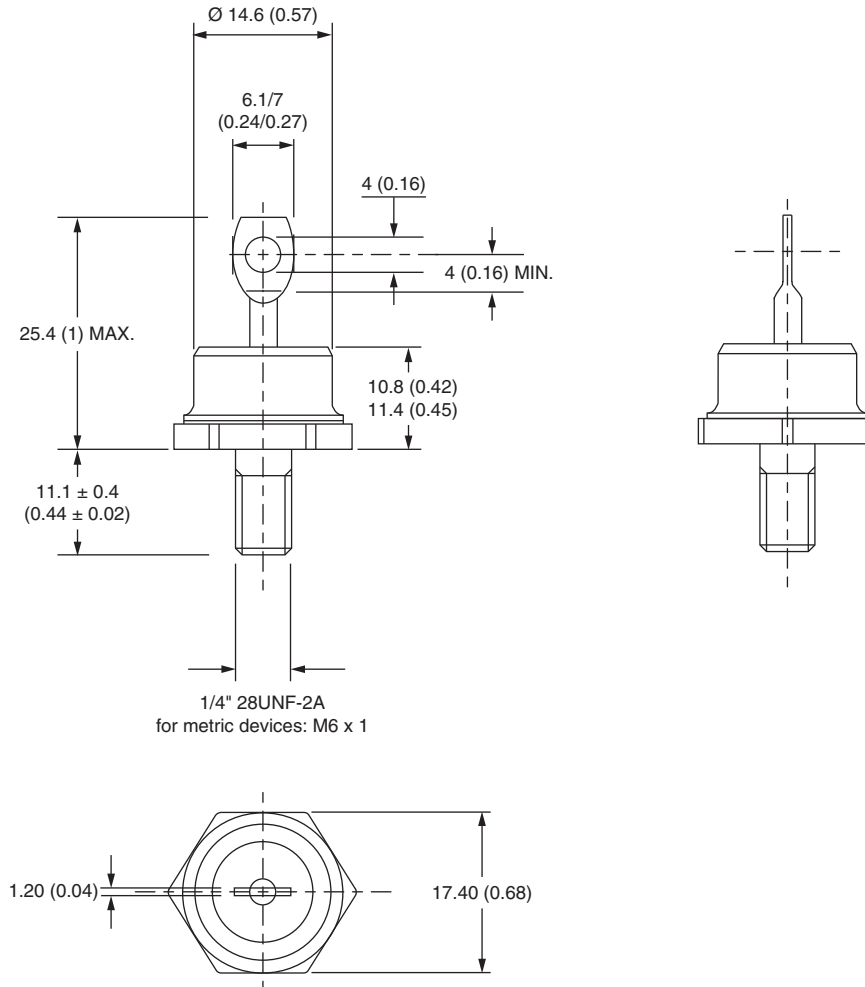
Device code	16	F	L	R	60	M	S02
	①	②	③	④	⑤	⑥	⑦

- 1** - Current code $I_{(AVG)}$ = Exact current rating
- 2** - F = Diode
- 3** - Omit = Standard recovery diode
L = Only for fast diode
- 4** - Omit = Stud forward polarity
R = Stud reverse polarity
- 5** - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- 6** - Outlines:
Omit = Stud base UNF thread
M = Stud base metric thread
- 7** - t_{rr} code only for fast diode (see Recovery Characteristics table)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95311

DO-203AB (DO-5) for 40HFL, 70HFL and 85HFL

DIMENSIONS FOR 40HFL/70HFL in millimeters (inches)



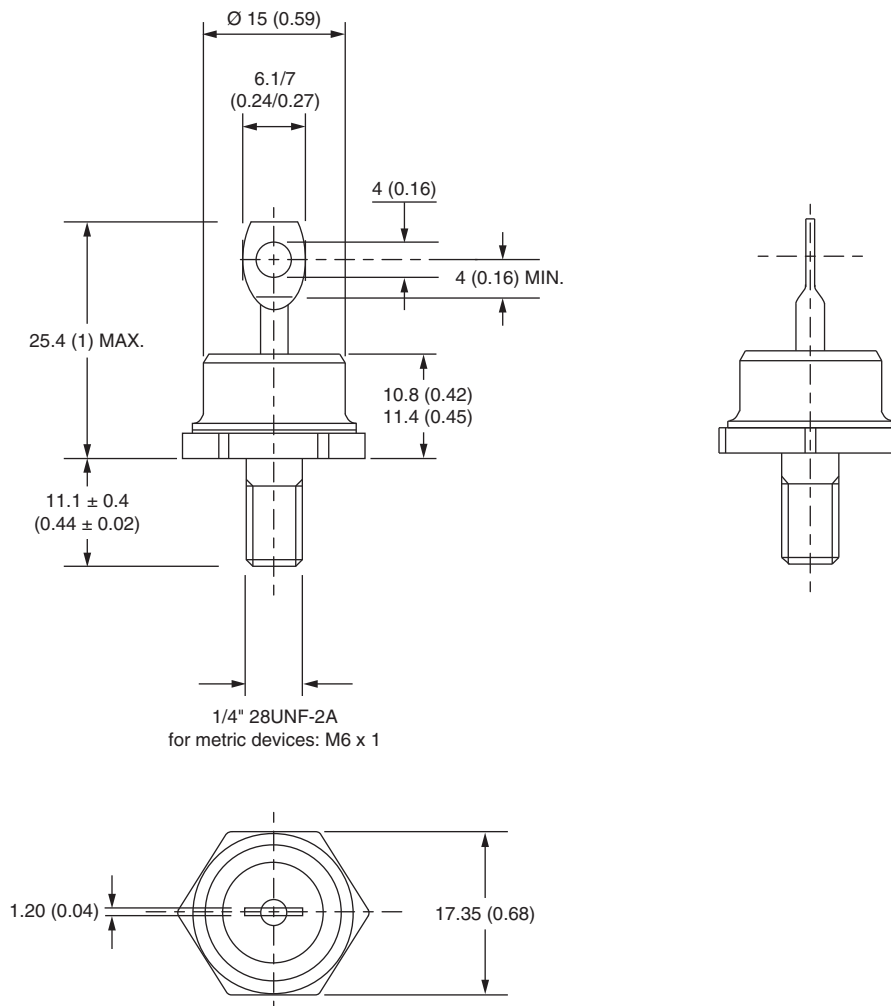
Outline Dimensions

Vishay Semiconductors

DO-203AB (DO-5) for
40HFL, 70HFL and 85HFL



DIMENSIONS FOR 85HFL in millimeters (inches)





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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Электрон
Связь**

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Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

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Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

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